

# Symposium 9C

## **Symposium 9C: Ceramics for Electricity; Direct Conversion Technology between Heat and Electricity**

### *Main Organizers*

- Ryoji Funahashi, AIST, Japan
- Kunihiro Koumoto, Nagoya University, Japan

### *Co-Organizers*

- Shinsuke Yamanaka, Osaka University, Japan
- Terry Tritt, Clemson University, USA
- George Nolas, University of South Florida, USA
- Lidong Chen, Shanghai Institute of Ceramics, Chinese Academy of Sciences, China
- Won Seon Seo, Korea Institute of Ceramic Engineering & Technology, Korea
- Harald Bottner, Fraunhofer Institute for Physical Measurement Techniques, Germany
- Antoine Maignan, Laboratoire CRISMAT/ENSICAEN, France

## **Oral Session**

**Wednesday, November 17**

Room: 1008

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### **9:00 - 10:30: Oxide I**

Chair: Ichiro Terasaki (Nagoya University, Japan)

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**9:00 - 9:15**

**S9C-001 Microstructure Control of Nano Phase-Separated Co-Mn-O System and its Effects on Thermoelectric Properties**

A. Kosuga<sup>1,2</sup>, K. Yubuta<sup>3</sup>, Y. Wang<sup>4</sup>, K. Kurosaki<sup>5</sup>, S. Yamanaka<sup>5</sup>, K. Koumoto<sup>4,6</sup>, R. Funahashi<sup>2,6</sup>; <sup>1</sup>Osaka Prefecture University, Japan, <sup>2</sup>National Institute of Advanced Industrial Science and Technology, Japan, <sup>3</sup>Tohoku University, Japan, <sup>4</sup>Nagoya University, Japan, <sup>5</sup>Osaka University, Japan, <sup>6</sup>Japan Science and Technology Agency, Japan

**9:15 - 9:30**

**S9C-002 Thermoelectric Properties of Perovskite-type Oxide System  $\text{Ca}_{1-x}\text{Nd}_{2x/3}\text{V}_{x/3}\text{MnO}_3$  Having A-site Vacancy**

H. Kawakami, M. Anzai, M. Saito, H. Yamamura; Kanagawa University, Japan

**9:30 - 9:45**

**S9C-003 Thermoelectric Properties and Figure of Merit of La-Doped (Ba,Sr)SnO<sub>3</sub> Solid Solutions**

M. Yasukawa<sup>1</sup>, T. Kono<sup>2</sup>, K. Ueda<sup>3</sup>, H. Yanagi<sup>4</sup>, S. W. Kim<sup>5</sup>, H. Hosono<sup>5</sup>; <sup>1</sup>Kochi National College of Technology, Japan, <sup>2</sup>Kochi Prefectural Industrial Technology Center, Japan, <sup>3</sup>Kyushu Institute of Technology, Japan, <sup>4</sup>University of Yamanashi, Japan, <sup>5</sup>Tokyo Institute of Technology, Japan

**9:45 - 10:00**

**S9C-004 Thermal and Electrical Properties of Metal Oxides with Rattling Cations in Cage-like Structure**

M. Ohtaki, S. Miyaishi; Kyushu University, Japan

**10:00 - 10:30**

**S9C-005 Structures and Thermoelectric Properties of Indium Based Oxide Compounds (Invited)**

E. Guilmeau, S. D. Bhamé, T. Zhou, B. Raveau; Laboratoire CRISMAT, France

**10:30 - 10:45 Break**

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### 10:45 - 12:15: Oxide II

Chair: Emmanuel Guilmeau (CRISMAT Laboratory, France)

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10:45 - 11:15

**S9C-006 Thermoelectricity Enhanced by Spin-State Disorder in the Perovskite Oxide  $\text{La}_{1-x}\text{Sr}_x\text{Co}_{1-y}\text{Rh}_y\text{O}_3$  (Invited)**

I. Terasaki<sup>1</sup>, S. Shibusaki<sup>2</sup>, S. Asai<sup>1</sup>, N. Furuta<sup>1</sup>, Y. Yasui<sup>1</sup>; <sup>1</sup>Nagoya University, Japan, <sup>2</sup>Waseda University, Japan

11:15 - 11:30

**S9C-007 Monolithic Micro ThermoElectric Generator Based on Multi Layer Ceramic Capacitor Technology**

S. Funahashi, S. F. Hayashi, T. Nakamura, K. Kageyama; Murata Manufacturing Co.,Ltd., Japan

11:30 - 11:45

**S9C-008 Role of Nb-doped Grain Boundaries in Nano-grained Thermoelectric Ceramics of La-doped  $\text{SrTiO}_3$**

Y. Wang<sup>1</sup>, C. Wan<sup>1,2</sup>, N. Wang<sup>1</sup>, Y. Ba<sup>1</sup>, K. Koumoto<sup>1,2</sup>; <sup>1</sup>Nagoya University, Japan, <sup>2</sup>Japan Science and Technology Agency, Japan

11:45 - 12:00

**S9C-009 Local Magnetic Properties in the  $\text{CoO}_2$  Layer in Layered Thermoelectric Cobalt Dioxides**

T. Takami<sup>1</sup>, M. Itoh<sup>1</sup>, H. Nozaki<sup>2</sup>, H. Itahara<sup>2</sup>, J. Sugiyama<sup>2</sup>; <sup>1</sup>Nagoya University, Japan, <sup>2</sup>Toyota Central Research and Development Labs. Inc., Japan

12:00 - 12:15

**S9C-010 Large Anisotropic Thermoelectricity in the Perovskite Related Layered Structure:  $\text{Sr}_n\text{Nb}_n\text{O}_{3n+2}$  (n=4, 5)**

A. Sakai, K. Takahashi, H. Adadchi, T. Kanno; Panasonic Corporation, Japan

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### 13:30 - 15:00: Chalcogenide

Chair: Clotilde Boulanger (Universite Paul Verlaine Metz LEM IJL, France)

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13:30 - 13:45

**S9C-011 Low-Thermal-Conductivity  $(MS)_{1+x}(\text{TiS}_2)_2$  (M = Pb, Bi, Sn) Misfit Layer Compounds for Bulk Thermoelectric Materials**

C. Wan<sup>1,2</sup>, Y. Wang<sup>1,2</sup>, N. Wang<sup>1</sup>, K. Koumoto<sup>1,2</sup>; <sup>1</sup>Nagoya University, Japan, <sup>2</sup>Japan Sciece and Technology Agency, Japan

13:45-14:00

**S9C-012 Effect of Transition Metal Filling on Thermoelectric Properties of Chevrel Phase Sulfides**

M. Ohta, A. Yamamoto, H. Obara, M. Kunii, H. Nishiate, K. Ueno; National Institute of Advanced Industrial Science and Technology, Japan

14:00 - 14:15

**S9C-013 Effect of Vacancy Distribution on the Lattice Thermal Conductivity of  $\text{Ga}_2\text{Se}_3$**

K. Kurosaki<sup>1</sup>, C. Kim<sup>1</sup>, M. Ishimarru<sup>1</sup>, Y. Ohishi<sup>1</sup>, H. Muta<sup>1</sup>, S. Yamanaka<sup>1,2</sup>; <sup>1</sup>Osaka University, Japan, <sup>2</sup>University of Fukui, Japan

14:15 - 14:30

**S9C-014 Thermoelectric Properties of  $\text{GaSb-Ga}_2\text{Te}_3$  and  $\text{InSb-In}_2\text{Te}_3$  Alloys**

C. Kim<sup>1</sup>, K. Kurosaki<sup>1</sup>, Y. Usui<sup>1</sup>, M. Ishimaru<sup>1</sup>, H. Muta<sup>1</sup>, S. Yamanaka<sup>1,2</sup>; <sup>1</sup>Osaka University, Japan, <sup>2</sup>University of Fukui, Japan

14:30 - 15:00

**S9C-015 Properties of Robust Thermoelectric Materials Prepared by Non-Equilibrium Synthesis Method for Energy Conversion (Invited)**

Q. Li; Brookhaven National Laboratory, USA

15:00 - 15:15 Break

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## 15:15 - 17:15: Bismuth Telluride and Silicide

Chair: Qiang Li (Brookhaven National Laboratory, USA)

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15:15 - 15:45

### S9C-016 Electrodeposition Ability for Tailoring Morphology and Thermoelectric Behavior of Bismuth Telluride Nanowires (Invited)

C. Boulanger<sup>1</sup>, C. Frantz<sup>1</sup>, N. Stein<sup>1</sup>, Y. Zhang<sup>2</sup>, L. Gravier<sup>3</sup>; <sup>1</sup>Université de Metz 1bd Arago, France, <sup>2</sup>Université de Metz Ile du Saulcy, France, <sup>3</sup>HEIG-Vd, Suisse

15:45 - 16:00

### S9C-017 Electrodeposition of of Bi<sub>2</sub>Te<sub>3</sub> Based Thermoelectric Micro-pillar Arrays

J.-F. Li, D.-W. Liu; Tsinghua University, China

16:00 - 16:15

### S9C-018 Preparation of $\beta$ -FeSi<sub>2</sub> and MnSi<sub>1.7+ $\delta$</sub> Bulks from Metal Compact Bodies Using a Na-Si Melt and Their Thermoelectric Properties

T. Yamada, E. Kariya, H. Morito, Y. Miyazaki, J. Takahashi, H. Yamane; Tohoku University, Japan

16:15 - 16:30

### S9C-019 Valence Electron Control in Higher Manganese Silicide MnSi<sub>y</sub>

Y. Miyazaki, Y. Saito, Y. Kikuchi, K. Hayashi, K. Yubuta, T. Kajitani; Tohoku University, Japan

16:30 - 16:45

### S9C-020 Structural Investigation and Thermoelectric Power of Fe-Si Compound

A. Sakulkalavek, S. Kiatgamolchai; Chulalongkorn University, Thailand

16:45 - 17:15

### S9C-021 Advanced Thermoelectric Materials and Components for Radioisotope Thermoelectric Generators for Space Power Applications (Invited)

T. Caillat; California Institute of Technology, USA

## Thursday, November 18

Room: 1008

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## 9:00 - 10:45: Skutterudite and Heusler

Chair: Toshihiro Takabatake (Hiroshima University, Japan)

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9:00 - 9:15

### S9C-022 Thermoelectric Properties of Tl<sub>x</sub>(Co<sub>1-y</sub>Rh<sub>y</sub>)<sub>4</sub>Sb<sub>12</sub>

A. Harnwungmoung<sup>1,2</sup>, K. Kurosaki<sup>1</sup>, H. Muta<sup>1</sup>, S. Yamanaka<sup>1,3</sup>; <sup>1</sup>Osaka University, Japan, <sup>2</sup>Rajamangala University of Technology Suvarnabhumi, Thailand, <sup>3</sup>University of Fukui, Japan

9:15 - 9:30

### S9C-023 High Performance In<sub>x</sub>Ce<sub>y</sub>Co<sub>4</sub>Sb<sub>12</sub> Thermoelectric Materials with *In-Situ* Nanostructured InSb Phase

H. Li<sup>1</sup>, X. Tang<sup>1</sup>, Q. Zhang<sup>1</sup>, C. Uher<sup>1,2</sup>; <sup>1</sup>Wuhan University of Technology, China, <sup>2</sup>University of Michigan, USA

9:30 - 10:00

### S9C-024 What Do We Learn from Study on Multiple-filled Skutterudites? (Invited)

W. Zhang<sup>1</sup>, L. Chen<sup>1</sup>, J. Yang<sup>2</sup>, X. Shi<sup>1</sup>, L. Xi<sup>1</sup>, X. Shi<sup>1</sup>; <sup>1</sup>Chinese Academy of Sciences, China, <sup>2</sup>General Motors R&D, USA

10:00 - 10:30

### S9C-025 Development of Thermoelectric Materials Based on Fe<sub>2</sub>VAl Heusler Compound for Energy Harvesting Applications (Invited)

Y. Nishino; Nagoya Institute of Technology, Japan

10:30 - 10:45

**S9C-026 Origin of Large Thermoelectric Power in Off-stoichiometric Fe<sub>2</sub>VAl-based Alloys**

K. Soda<sup>1</sup>, S. Harada<sup>1</sup>, M. Kato<sup>1</sup>, S. Yagi<sup>1</sup>, Y. Sandaiji<sup>2</sup>, Y. Nishino<sup>2</sup>; <sup>1</sup>Nagoya University, Japan, <sup>2</sup>Nagoya Institute of Technology, Japan

**10:45 - 12:00: Clathrate and Others**

Chair: Wenqing Zhang (Shanghai Institute of Ceramics, China)

10:45 - 11:15

**S9C-027 Tellurium-free Thermoelectric Module Based on a Clathrate Compound Ba<sub>8</sub>Ga<sub>16</sub>Sn<sub>30</sub> with p- and n-type Carriers (Invited)**

T. Takabatake<sup>1</sup>, Y. Saiga<sup>1</sup>, S. Deng<sup>1</sup>, K. Suekuni<sup>1</sup>, A. Yamamoto<sup>2</sup>, K. Kishimoto<sup>3</sup>, K. Nagase<sup>2</sup>, H. Obara<sup>2</sup>, K. Ueno<sup>2</sup>, T. Koyanagi<sup>3</sup>, K. Akai<sup>1</sup>, Y. Kono<sup>4</sup>, T. Taguchi<sup>4</sup>, N. Ohya<sup>4</sup>, K. Fukuda<sup>5</sup>; <sup>1</sup>Hiroshima University, Japan, <sup>2</sup>National Institute of Advanced Industrial Science and Technology, Japan, <sup>3</sup>Yamaguchi University, Japan, <sup>4</sup>DENSO Corp., Japan, <sup>5</sup>KELK Ltd., Japan

11:15 - 11:30

**S9C-028 Influence of Defect on the Thermoelectric Properties of YbB<sub>6</sub>**

K. Kayamura<sup>1</sup>, K. Inayoshi<sup>1</sup>, H. Kitagawa<sup>2</sup>, M. Takeda<sup>1</sup>; <sup>1</sup>Nagaoka University of Technology, Japan, <sup>2</sup>Shimane University, Japan

11:30 - 11:45

**S9C-029 Rapid Solidification Methods for Fabrication of Novel Thermoelectric Materials**

X. Tang<sup>1</sup>, H. Li<sup>1</sup>, W. Xie<sup>1,3</sup>, Y. Yan<sup>1</sup>, Q. Zhang<sup>1</sup>, C. Uher<sup>2</sup>, T. M. Tritt<sup>3</sup>; <sup>1</sup>Wuhan University of Technology, China, <sup>2</sup>University of Michigan, USA, <sup>3</sup>Clemson University, USA

11:45 - 12:00

**S9C-030 Thermoelectric Properties of Conducting Polyaniline/BaTiO<sub>3</sub> Nanoparticle Composite Films**

H. Anno<sup>1</sup>, K. Yamaguchi<sup>1</sup>, T. Nakabayashi<sup>1</sup>, H. Kurokawa<sup>2</sup>, F. Akagi<sup>1</sup>, M. Hojo<sup>1</sup>, N. Toshima<sup>1</sup>; <sup>1</sup>Tokyo University of Science, Yamaguchi, Japan, <sup>2</sup>Toda Kogyo Corp., Japan

**13:15 - 14:30: Application I**

Chair: Anke Weidenkaff (Empa, Swiss Federal Laboratories for Materials Science and Technology, Switzerland)

13:15 - 13:45

**S9C-031 Progress in TE Materials and Devices and Solar PV-TE Hybrid Power Generation System in China (Invited)**

Q.-J. Zhang; Wuhan University of Technology, China

13:45 - 14:00

**S9C-032 Application of High-Thermoelectric-Power Materials to Self-Cooling Device**

H. Nakatsugawa<sup>1</sup>, Y. Okamoto<sup>2</sup>, S. Yamaguchi<sup>3</sup>, T. Kawahara<sup>3</sup>; <sup>1</sup>Yokohama National University, Japan, <sup>2</sup>National Defence Academy, Japan, <sup>3</sup>Chubu University, Japan

14:00 - 14:30

**S9C-033 A High Packing Density Micro-thermoelectric Power Generator Fabricated by Electrochemical MEMS Technology (Invited)**

W. Wang<sup>1</sup>, Y.-T. Jin<sup>1</sup>, Y.-B. Zhu<sup>1</sup>, M. Bian<sup>1</sup>, X. Liao<sup>1</sup>, H. Li<sup>2</sup>, J.-P. Gao<sup>3</sup>; <sup>1</sup>School of Chemical Engineering and Technology, China, <sup>2</sup>School of Material science and engineering, China, <sup>3</sup>School of Science Tianjin University, China

14:30 - 14:45 **Break**

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## 14:45 - 16:00: Application II

Chair: Hiroaki Anno (Tokyo University of Science, Yamaguchi, Japan)

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14:45 - 15:00

**S9C-034 Thin Film Thermopile Array Generator Using Ceramic Catalytic Combustor**

W. Shin, T. Nakashima, M. Nishibori, N. Izu, T. Itoh, Y. Kinemuchi, Y. Fujishiro, I. Matsubara; National Institute of Advanced Industrial Science and Technology, Japan

15:00 - 15:30

**S9C-035 Development of Unconventional Thermoelectrics for Solar Energy Converters (Invited)**

A. Weidenkaff, M. Aguirre, N. Schäuble, P. Tomes, L. Karvonen, M. Trottmann; Empa, Switzerland

15:30 - 16:00

**S9C-036 Power Generation of Cascaded Thermoelectric Systems (Invited)**

R. Funahashi<sup>1,2</sup>, S. Urata<sup>1</sup>, T. Urata<sup>1,2</sup>, Y. Matsumura<sup>1</sup>, K. Iwasaki<sup>1</sup>; <sup>1</sup>National Institute of Advanced Industrial Science and Technology, Japan, <sup>2</sup>Japan Science and Technology Agency, Japan

## Poster Session

### Tuesday, November 16

Room: Event Hall

12:00 - 14:00

**S9C-P001 Thermoelectric Properties of Sb-doped Mg<sub>2</sub>Si Prepared by Solid State Synthesis**

J.-Y. Jung, K.-H. Park, I.-H. Kim; Chungju National University, Korea

**S9C-P002 Thermoelectric Properties of Single Crystalline Clathrate Ba<sub>8</sub>Al<sub>x</sub>Si<sub>46-x</sub>**

N. Mugita, Y. Nakahohara, T. Motooka, R. Teranishi, S. Munetoh; Kyushu University, Japan

**S9C-P003 Thermoelectric Properties and Oxidation Behavior of Magnesium Silicide**

J. Tani, M. Takahashi, H. Kido; Osaka Municipal Technical Research Institute, Japan

**S9C-P004 Thermoelectric Properties of  $\beta$ -FeSi<sub>2</sub> Based Dispersed and Nanodispersed HIPed Bodies**

S. Nishiyama, Y. Sakurai, T. Umetsu; Chiba University, Japan

**S9C-P005 Preparation and Thermoelectric Properties of (Mn<sub>1-x</sub>Cr<sub>x</sub>)Si<sub>y</sub> ( $y \sim 1.7$ ) Solid Solution**

Y. Kikuchi, Y. Saito, K. Hayashi, Y. Miyazaki, K. Yubuta, T. Kajitani; Tohoku University, Japan

**S9C-P006 Thermoelectric Characteristics of Doped Mg<sub>2</sub>Si Fabricated by Spark Plasma Sintering Method**

K. H. Kim<sup>1</sup>, S. M. Choi<sup>1</sup>, I. H. Kim<sup>2</sup>, S. U. Kim<sup>3</sup>, W. S. Seo<sup>1</sup>; <sup>1</sup>Korea Institute of Ceramic Engineering and Technology, Korea, <sup>2</sup>Chungju National University, Korea, <sup>3</sup>Research Institute of Industrial Science and Technology, Korea

**S9C-P007 Effect of Na Addition on Electric Properties of Ca<sub>2</sub>Si Sintered Compacts**

C. Wen<sup>1</sup>, T. Nonomura<sup>1</sup>, A. Kato<sup>2</sup>, K. Isobe<sup>3</sup>, Y. Kubota<sup>1</sup>, T. Nakamura<sup>1</sup>, Y. Hayakawa<sup>1</sup>, H. Tatsuoka<sup>1</sup>; <sup>1</sup>Shizuoka University, Japan, <sup>2</sup>FDK Corporation, Japan, <sup>3</sup>Industrial Research Institute of Shizuoka Prefecture, Japan

**S9C-P008 Syntheses and Electrical Properties of Hexagonal Phase Group VI Metal Silicide Powders, Sintered Compacts and Bulk Crystals**

T. Nonomura<sup>1</sup>, C. Wen<sup>1</sup>, M. Yamashita<sup>1</sup>, K. Isobe<sup>2</sup>, A. Kato<sup>3</sup>, Y. Kubota<sup>1</sup>, T. Nakamura<sup>1</sup>, Y. Hayakawa<sup>1</sup>, H. Tatsuoka<sup>1</sup>; <sup>1</sup>Shizuoka University, Japan, <sup>2</sup>Industrial Research Institute of Shizuoka Prefecture, Japan, <sup>3</sup>FDK Corporation, Japan

**S9C-P009 Electrical and Mechanical Properties of a MoSi<sub>2</sub>-WSi<sub>2</sub>-Alumomagnesium Silicate Composite**

D. Titov<sup>1</sup>, Y. Kargin<sup>1</sup>, N. Popova<sup>2</sup>, V. Gorshkov<sup>3</sup>; <sup>1</sup>IMET RAS, Russia, <sup>2</sup>Mendeleyev University of Chemical Technology, Russia, <sup>3</sup>ISMAN RAS, Russia

- S9C-P010 Structural and Thermoelectric Properties of Sintered Silicon Clathrates:  $Ba_{8-x}A_xGa_{16}Si_{30}$  (A=Sr, Eu; x=0-2) Nominal Compositions**  
T. Nakabayashi<sup>1,3</sup>, M. Hokazono<sup>1,3</sup>, H. Anno<sup>1,3</sup>, Y. Ba<sup>2,3</sup>, K. Koumoto<sup>2,3</sup>; <sup>1</sup>Tokyo University of Science, Yamaguchi, Japan, <sup>2</sup>Nagoya University, Japan, <sup>3</sup>Japan Science and Technology Agency, CREST, Japan
- S9C-P011 The Characteristics and Growth Mechanism of  $Bi_2Te_3$  Thin Film Grown on ITO Glass Substrate**  
 J.-Y. Yang<sup>1</sup>, M.-H. Lin<sup>2</sup>, S.-T. Choi<sup>3</sup>, W.-C. Jhong<sup>3</sup>, T.-C. Cheng<sup>2</sup>, W.-H. Lin<sup>2</sup>; <sup>1</sup>National Nano Device Laboratories, Taiwan, <sup>2</sup>National Kaohsiung University of Applied Sciences, Taiwan, <sup>3</sup>National Cheng Kung University, Taiwan
- S9C-P012 The Thermoelectric Performance of Nano-SiC Doped  $Bi_{0.3}Sb_{1.7}Te_3$  Composites at Low Temperature**  
M. Zhou, Z. Chen, L. Li; Chinese Academy of Sciences, China
- S9C-P013 Preparation and Thermoelectric Properties of  $Ru_{1-x}Fe_xAl_2$**   
S. Takahashi<sup>1</sup>, H. Muta<sup>1</sup>, K. Kurosaki<sup>1</sup>, S. Yamanaka<sup>1,2</sup>; <sup>1</sup>Osaka University, Japan, <sup>2</sup>University of Fukui, Japan
- S9C-P014 Doping Effects on Thermoelectric Properties of Off-Stoichiometric  $Fe_2VAl$  Alloys**  
Y. Tamada, Y. Sandaiji, Y. Nishino; Nagoya Institute of Technology, Japan
- S9C-P015 Transport Properties of  $ZrNi_{1.05}Sn$  Half-Heusler Compound**  
H. Muta<sup>1</sup>, K. Furo<sup>1</sup>, Y. Ohishi<sup>1</sup>, K. Kurosaki<sup>1</sup>, S. Yamanaka<sup>1,2</sup>; <sup>1</sup>Osaka University, Japan, <sup>2</sup>University of Fukui, Japan
- S9C-P016 Rietveld Refinement of Crystal Structure of  $\beta$ - $Zn_4Sb_3$  with Partial Substitution of In for Sb**  
S.-D. Cheng; Wuhan University of Technology, China
- S9C-P017 Phase Transformation in  $In_2Se_3$ - $In_4Te_3$  Mixture and Its Effect on Thermoelectric Properties**  
 J. Y. Cho<sup>1,2</sup>, M. Jung<sup>1</sup>, Y. S. Lim<sup>1</sup>, W.-S. Seo<sup>1</sup>, H.-H. Park<sup>2</sup>; <sup>1</sup>Korea Institute of Ceramic Engineering and Technology, Korea, <sup>2</sup>Yonsei University, Korea
- S9C-P018 Thermoelectric Properties of  $(AgSbTe_2)_{1-x}(Pb_{0.16}Ge_{0.84}Te)_x$  (x = 0.75, 0.80, 0.85, and 0.90)**  
A. Yusufu<sup>1</sup>, K. Kurosaki<sup>1</sup>, H. Muta<sup>1</sup>, S. Yamanaka<sup>1,2</sup>; <sup>1</sup>Osaka University, Japan, <sup>2</sup>University of Fukui, Japan
- S9C-P019 Synthesis of  $Bi_2Te_3$  Nanosheets using Polyol Process**  
S. Nishiwaki, T. Itoh; Nagoya University, Japan
- S9C-P020 Effect of Alloying on the Thermoelectric Properties of Divalent Hexaborides**  
K. Inayoshi, K. Iguchi, M. Takeda; Nagaoka University of Technology, Japan
- S9C-P021 Preparation and Characterization of Planetary Ball Milled Si-based Clathrates and Their Spark Plasma Sintered Materials**  
 R. Shirataki, M. Hokazono, T. Nakabayashi, H. Anno; Tokyo University of Science, Yamaguchi, Japan Science and Technology Agency, CREST, Japan
- S9C-P022 Fabrication of Layered  $TiS_2$ -based Thermoelectric Elements by Using Centrifugal Heating Method**  
T. Aoki<sup>1</sup>, C. L. Wan<sup>2</sup>, H. Ishiguro<sup>1</sup>, H. Morimitsu<sup>1</sup>, K. Koumoto<sup>2</sup>; <sup>1</sup>Sinto Kogio, Ltd., Japan, <sup>2</sup>Nagoya University, Japan
- S9C-P023 Controlling Independently the Electric and Thermal Properties by Shrinking the Particle Size down to Nanosize**  
T. Takami<sup>1</sup>, M. Horibe<sup>1</sup>, M. Itoh<sup>1</sup>, J.-G. Cheng<sup>2</sup>, J.-S. Zhou<sup>2</sup>, J. B. Goodenough<sup>2</sup>; <sup>1</sup>Nagoya University, Japan, <sup>2</sup>University of Texas at Austin, USA
- S9C-P024 Thermoelectric Properties of  $ZnMgO/ZnO$  Multilayer**  
M. Nishiguchi, K. Hayashi, Y. Miyazaki, T. Kajitani; Tohoku University, Japan
- S9C-P025 Electrical Properties of  $Fe_2O_3$  Added  $La_2CuO_4$  Sintered Bodies**  
Y. Okada, S. Nishiyama; Chiba University, Japan
- S9C-P026 Microstructure and Thermoelectric Properties of Cu-doped  $\alpha$ - $Fe_2O_3$  for Power Generation**  
G. W. Lee<sup>1</sup>, H. K. Hwang<sup>1</sup>, Y. G. Choi<sup>1</sup>, W. S. Seo<sup>2</sup>, K. Park<sup>1</sup>; <sup>1</sup>Sejong University, Korea, <sup>2</sup>Korea Institute of Ceramic Engineering and Technology, Korea



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- S9C-P027 Electric and Thermoelectric Properties in  $\text{Cu}_{1+x}\text{Mn}_{2-x}\text{O}_{4+5}$**   
K. Fukao, H. Nakayama, N. Watnabe, F. Munakata; Tokyo City University, Japan
- S9C-P028 Thermoelectric Properties of Bulk Ga Doped ZnO**  
P. Jood, G. Peleckis, X. L. Wang, S. X. Dou; University of Wollongong, Australia
- S9C-P029 Microstructure and High-temperature Thermoelectric Properties of  $\text{Zn}_{1-x}\text{Ce}_x\text{O}$  ( $0 \leq x \leq 0.02$ )**  
H. K. Hwang<sup>1</sup>, Y. G. Choi<sup>1</sup>, W. S. Seo<sup>2</sup>, K. Park<sup>1</sup>; <sup>1</sup>Sejong University, Korea, <sup>2</sup>Korea Institute of Ceramic Engineering and Technology, Korea
- S9C-P030 Structure and Thermoelectric Properties of Double-Perovskite Oxides  $\text{A}_2\text{FeMoO}_6$  and  $\text{A}_2\text{MnMoO}_6$  with A-site Substitution**  
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- S9C-P031 Thermoelectric Properties of p-type Perovskite Compounds  $\text{LaCoO}_3$  Systems Containing the A-site Vacancy**  
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- S9C-P032 Microstructure and Thermoelectric Properties of Ag-added  $\text{Na}(\text{Co}_{1-x}\text{Ag}_x)_2\text{O}_4$  ( $0 \leq x \leq 0.25$ ) Thermoelectric Materials**  
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- S9C-P033 Crystal Growth and Power Factor of  $\text{Ba}_{12}\text{Co}_{11}\text{O}_{33-5}$  Having a Pseudo-one-dimensional Structure**  
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- S9C-P034 n-type Oxide Thermoelectric Materials  $(\text{CaO})(\text{CaMnO}_3)_n$  ( $n = 1, 2, 3 \text{ \& } \infty$ )**  
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